

**ON**  
**ELEMENTARY**  
**PROCESSES**  
**AND**  
**CHEMICAL**  
**REACTIONS**  
**IN**  
**LOW**  
**TEMPERATURE**  
**PLASMA**



**10<sup>th</sup>**

*Symposium*  
*s y m p o s i u m*

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**Stará Lesná, High Tatras**  
**September 5 to 9, 1994**



## REMOVAL OF NO<sub>x</sub> IN CORONA DISCHARGE AT THE ATMOSPHERIC PRESSURE WITH INNER ELECTRODE MATERIAL VARIATION

K. Hensel, M. Morvová (Bratislava)

The spatial chemical processes and effectiveness of NO<sub>x</sub> removal at relatively high pressures under the influence of corona discharge was investigated. Also the influence of inner electrode (wire) materials on discharge behaviour and the surface products analyses of the outer electrode are reported. Experiments were carried out using corona discharge of both polarities and products were analysed by infrared (IR) absorption spectrometry. A special attention was paid to calibration measurements of NO and NO<sub>2</sub> at various pressures.

Experimental set-up consist of wire wound on the glass tube placed over the plate electrode and situated in the IR absorption gas cell. Different material of inner electrode (wire) was treated in experiments.

The results obtained showed that :

- negative corona discharge is more stable, but its deNO<sub>x</sub> effect is mostly very unpredictable (deNO is usually very effective but NO<sub>2</sub> more or less increase when also NO is present)
- in positive polarity deNO efficiency is about the same, but in all cases also NO<sub>2</sub> decrease.
- both deNO and deNO<sub>2</sub> processes at lower partial pressure is more effective in positive corona (50 Torr). At higher pressures (more than 200 Torr) is effect of both polarities about the same.
- experiments showed that mostly deNO<sub>2</sub> processes is material depending.
- changes in N<sub>2</sub>O concentrations seems to be very important.

## CORONA DISCHARGE DEVICE FOR deNO<sub>x</sub> PROCESSES.

R. Gašparík, M. Morvová (Bratislava)

Device for decomposition of NO<sub>x</sub> and other components of combustion exhausts on the base of the corona discharge and coaxial geometry was designed for 10 Nm<sup>3</sup>/h flow volume of flue gases and was realized completely, with gas flow dynamic system and system to water or water solution spraying by the use of ultrasound. This equipment contains 24 discharge tubes in two sectors. Various materials of electrodes was tested in three completely realized systems.

Following materials was used: cooper, stainless steel and brass for high voltage electrodes and brass and aluminium for low voltage electrodes.

These options were realized because of assumed catalytic effects of electrode material. The experimental evidence for this was gained during measurements performed.

Measurements was contractly effected in glass-work plant named ORNELA in Czech Republic.

## Energy dependences of reactions of Si<sup>+</sup> with H<sub>2</sub>O and H<sub>2</sub>S

J. Glosík<sup>1,2</sup>, P. Zakouřil<sup>1,2</sup> and W. Lindinger<sup>1</sup> (<sup>1</sup>Innsbruck, <sup>2</sup>Prague)

The rate coefficients for the reactions of Si<sup>+</sup> with H<sub>2</sub>O and H<sub>2</sub>S have been measured as a function of reactant ion / reactant neutral average center-of-mass kinetic energy ( $E_r$ ). The measurements were performed using a selected ion flow drift tube operated at 300K with helium buffer gas. Both reactions have rate coefficients close to their collisional values at ambient temperature and exhibit a pronounced  $E_r$  dependence. The rate coefficients of reaction of Si<sup>+</sup> with H<sub>2</sub>O producing SiOH<sup>+</sup> decrease by one order of magnitude with  $E_r$  increasing from 0.05 eV to 0.4 eV. The rate coefficient of the reaction of Si<sup>+</sup> with H<sub>2</sub>S, producing SiSH<sup>+</sup> and SiH<sup>+</sup>, is decreasing with  $E_r$  increasing from 0.05 to 2.5 eV. When considering the branching ratio, the reaction rate coefficient for channel producing SiSH<sup>+</sup> is decreasing by nearly two orders of magnitude. The reaction rate coefficient for channel producing SiH<sup>+</sup> is increasing with increasing  $E_r$  and at energies higher as 1 eV this channel is dominated.